

# **HVU145**

## Silicon Epitaxial Planar Pin Diode for Antenna Switching

REJ03G0437-0200

(Previous: ADE-208-1508A)

Rev.2.00 Dec 07, 2004

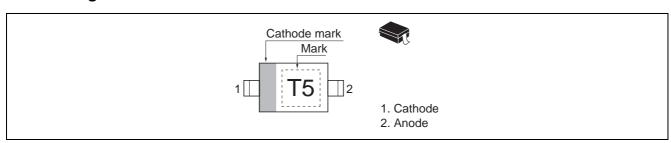
### **Features**

- An optimal solution for antenna switching in mobile phones.
- Low capacitance. (C =0.45 pF max)
- Low forward resistance. (rf =  $1.8 \Omega \text{ max}$ )
- <u>U</u>ltra small <u>Resin Package</u> (URP) is suitable for surface mount design.

### **Ordering Information**

| Type No. | Laser Mark | Package Code |
|----------|------------|--------------|
| HVU145   | T5         | URP          |

### **Pin Arrangement**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

| Item                 | Symbol         | Value       | Unit |
|----------------------|----------------|-------------|------|
| Reverse voltage      | V <sub>R</sub> | 60          | V    |
| Forward current      | I <sub>F</sub> | 50          | mA   |
| Power dissipation    | Pd             | 150         | mW   |
| Junction temperature | Tj             | 125         | °C   |
| Storage temperature  | Tstg           | −55 to +125 | °C   |

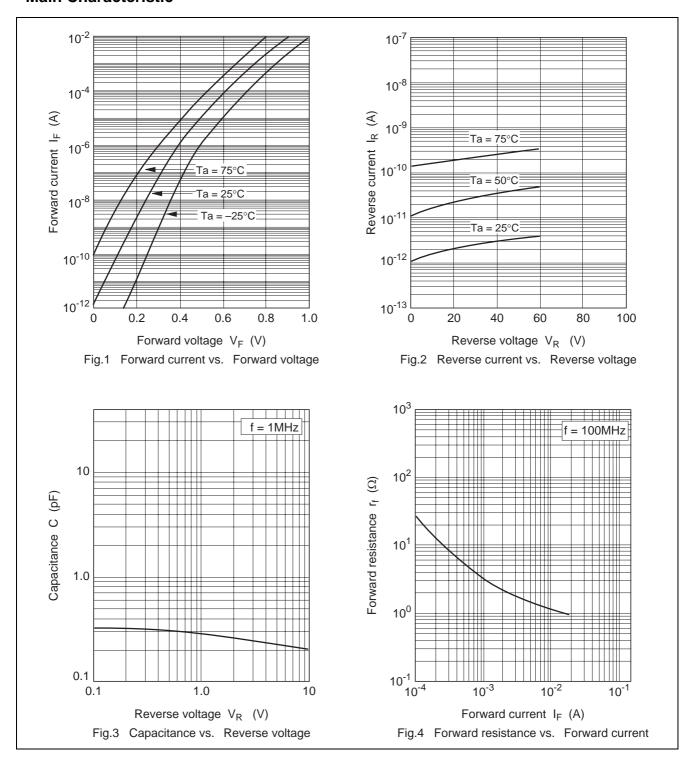
### **Electrical Characteristics**

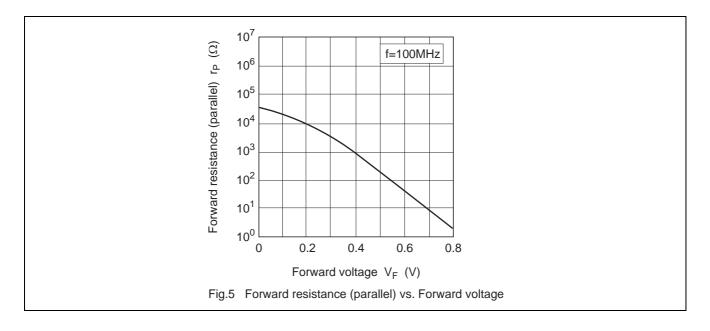
 $(Ta = 25^{\circ}C)$ 

| Item               | Symbol         | Min | Тур | Max  | Unit | Test Condition                                    |
|--------------------|----------------|-----|-----|------|------|---|
| Reverse current    | I <sub>R</sub> | _   | _   | 100  | nA   | V <sub>R</sub> = 60 V                             |
| Forward voltage    | $V_{F}$        | _   | _   | 0.9  | V    | I <sub>F</sub> = 2 mA                             |
| Capacitance        | С              | _   | _   | 0.45 | pF   | V <sub>R</sub> = 1 V, f = 1 MHz                   |
| Forward resistance | r <sub>f</sub> | _   | _   | 1.8  | Ω    | I <sub>F</sub> = 10 mA, f = 100 MHz               |
| ESD-Capability *1  | _              | 100 | _   | _    | V    | $C = 200 \text{ pF}, R = 0 \Omega$ , Both forward |
|                    |                |     |     |      |      | and reverse direction 1 pulse.                    |

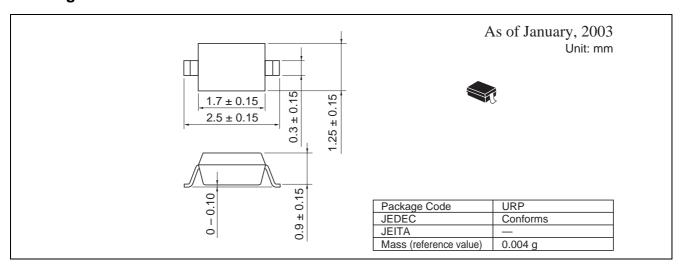
Note: 1. Failure criterion ;  $I_R > 100$  nA at  $V_R = 60$  V

### **Main Characteristic**





## **Package Dimensions**



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